## VS-10ETF10FP-M3, VS-10ETF12FP-M3

Vishay Semiconductors

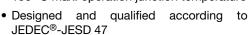
# Fast Soft Recovery Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	10 A			
$V_{R}$	1000 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.33 V			
I <sub>FSM</sub>	140 A			
t <sub>rr</sub>	80 ns			
T <sub>J</sub> max.	150 °C			
Snap factor	0.6			
Package	TO-220 FullPAK 2L			
Circuit configuration	Single			

#### **FEATURES**

- Glass passivated pellet chip junction
- 150 °C max. operation junction temperature





- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

#### **DESCRIPTION**

The VS-10ETF1..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
V <sub>RRM</sub>		1000, 1200	V			
I <sub>F(AV)</sub>	Sinusoidal waveform	10	٨			
I <sub>FSM</sub>		140	А			
t <sub>rr</sub>	1 A, 100 A/µs	80	ns			
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.33	V			
T <sub>J</sub>		-40 to +150	°C			

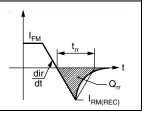
VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA			
VS-10ETF10FP-M3	1000	1100	4			
VS-10ETF12FP-M3	1200	1300	4			

# **VS-10ETF10FP-M3, VS-10ETF12FP-M3**

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 95 °C, 180° conduction half sine wave	10	
Maximum peak one cycle non-repetitive surge current	1	10 ms sine pulse, rated V <sub>RRM</sub> applied	115	Α
	IFSM	10 ms sine pulse, no voltage reapplied	140	
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	66	A <sup>2</sup> s
	1-1	10 ms sine pulse, no voltage reapplied	94	A-S
Maximum l²√t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	940	A²√s

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	10 A, T <sub>J</sub> = 25 °C		1.33	V
Forward slope resistance	rt	T <sub>J</sub> = 150 °C		22.9	mΩ
Threshold voltage	V <sub>F(TO)</sub>			0.96	V
Maximum reverse leakage current		T <sub>J</sub> = 25 °C	V - rotad V	0.1	mA
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	V <sub>R</sub> = rated V <sub>RRM</sub>	4	III/A

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> at 10 A <sub>pk</sub>	310	ns	
Reverse recovery current	I <sub>rr</sub>		4.7	Α	
Reverse recovery charge	Q <sub>rr</sub>	25 °C	1.05	μC	
Snap factor	S		0.6		



THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistar junction to case	nce	R <sub>thJC</sub>	DC operation	2.5	
Maximum thermal resistar junction to ambient	nce	$R_{thJA}$		62	°C/W
Typical thermal resistance case to heatsink	),	R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.5	
A managina aka uwai alak				2	g
Approximate weight				0.07	OZ.
Mounting torque —	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf $\cdot$ in)
Marking device			Case style TO-220 FullPAK 2L	10ETF10FP 10ETF12FP	



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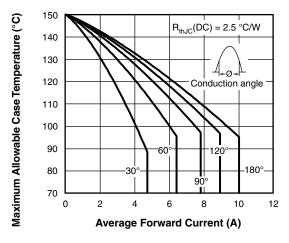


Fig. 1 - Current Rating Characteristics

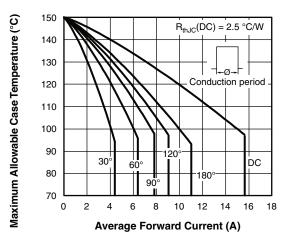


Fig. 2 - Current Rating Characteristics

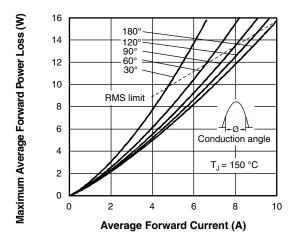


Fig. 3 - Forward Power Loss Characteristics

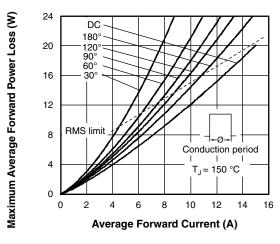


Fig. 4 - Forward Power Loss Characteristics

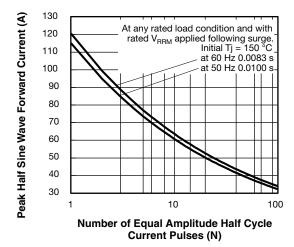


Fig. 5 - Maximum Non-Repetitive Surge Current

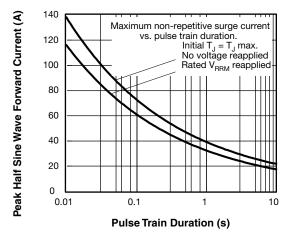


Fig. 6 - Maximum Non-Repetitive Surge Current

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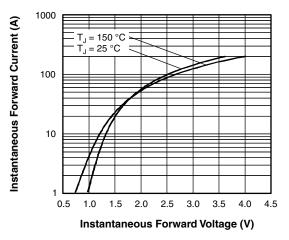


Fig. 7 - Forward Voltage Drop Characteristics

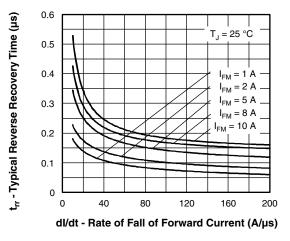


Fig. 8 - Recovery Time Characteristics,  $T_J = 25$  °C

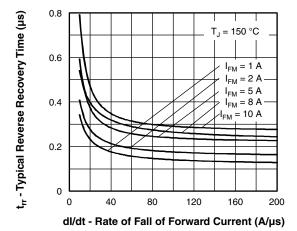


Fig. 9 - Recovery Time Characteristics,  $T_J = 150 \, ^{\circ}\text{C}$ 

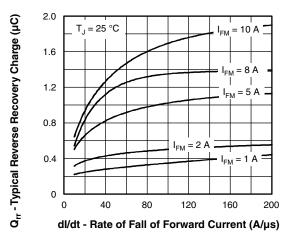


Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C

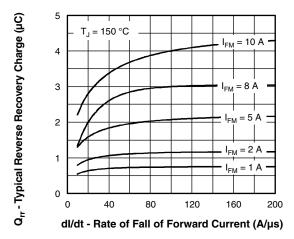


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C

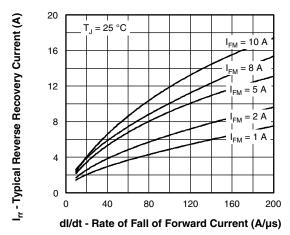


Fig. 12 - Recovery Current Characteristics,  $T_J = 25\ ^{\circ}\text{C}$ 

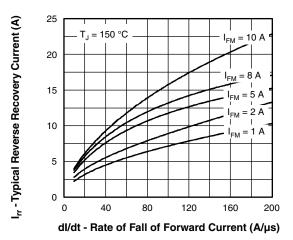


Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

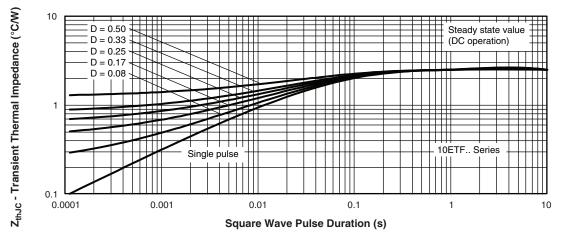


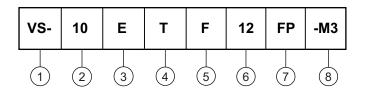
Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

# VS-10ETF10FP-M3, VS-10ETF12FP-M3

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#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

Current rating (10 = 10 A)

Circuit configuration:

E = single diode

Package:

T = TO-220

5 Type of silicon:

F = fast soft recovery rectifier

02 = 200 V Voltage code x 100 = V<sub>RRM</sub>

04 = 400 V 06 = 600 V

**FullPAK** 

Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETF10FP-M3	50	1000	Antistatic plastic tubes			
VS-10ETF12FP-M3	50	1000	Antistatic plastic tubes			

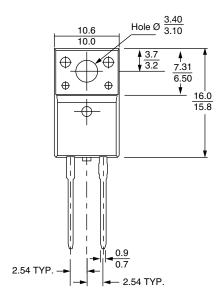
LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96157
Part marking information	www.vishay.com/doc?95392

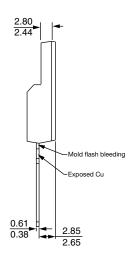


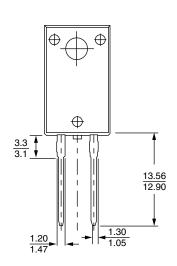
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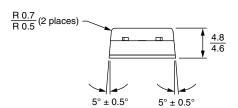
## 2L TO-220 FullPAK

#### **DIMENSIONS** in millimeters









Bottom view



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